## NSN 5961-01-229-7319

Transistor - Page 1 of 1

**Fiig:** A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-229-7319 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.450 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 140.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and 14.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source **Current Rating Per Characteristic:** 7.00 amperes drain current **Power Rating Per Characteristic:** 100.0 watts total power dissipation **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No